# UNITED STATES PATENT AND TRADEMARK OFFICE **CERTIFICATE OF CORRECTION**

PATENT NO.

: 6,771,019 B1

DATED

: August 3, 2004

INVENTOR(S): Wu et al.

It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

Page 1 of 2

## Column 41,

Line 32, after "phosphor deposits" insert --, said at least first and second phosphor deposits being formed from phosphors of different host materials --.

### Column 43,

Line 30, delete "a threshold voltage adjustment layer selected" and replace with -- the threshold voltage adjustment layer being selected --.

Line 61 delete "a threshold voltage adjustment layer selected" and replace with -- the threshold voltage adjustment layer being selected --.

### Column 44,

Line 51, delete "a threshold voltage" and replace with -- the threshold voltage --.

#### Column 45,

Lines 3-4, delete "a threshold voltage adjustment layer selected" and replace with -- the threshold voltage adjustment layer being selected --.

Line 64, after "dielectric layer" insert --, S is the dielectric strength of the dielectric layer --.

#### Column 49,

Line 30, delete "a threshold voltage adjustment layer selected" and replace with -- the threshold voltage adjustment layer being selected --.

Line 56, delete "a thickness" and replace with -- the thickness --.

Line 59, after "dielectric layer" insert --, S is the dielectric strength of the dielectric layer --.

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It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

# Column 52,

Lines 12-13, delete "a threshold voltage" and replace with -- the threshold voltage --. Lines 29-30, delete "a threshold voltage adjustment layer selected" and replace with -- the threshold voltage adjustment layer being selected --.

Signed and Sealed this

Eighth Day of February, 2005

JON W. DUDAS Director of the United States Patent and Trademark Office